



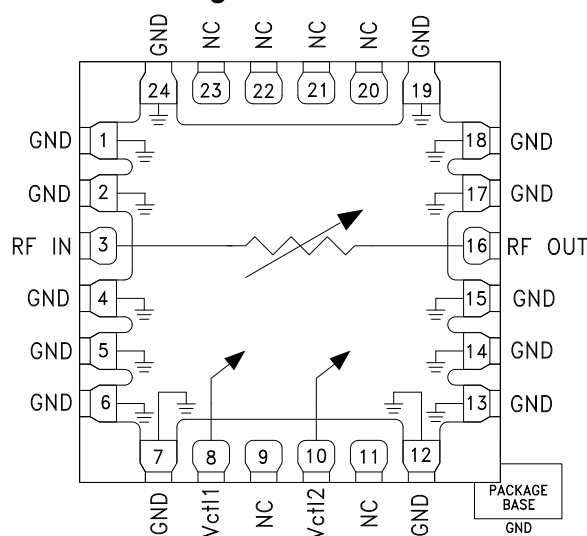
## GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

### Typical Applications

The HMC985LP4KE is ideal for:

- Point-to-Point Radio
- VSAT Radio
- Test Instrumentation
- Microwave Sensors
- Military, ECM & Radar

### Functional Diagram



### Features

- Wide Bandwidth: 10 - 40 GHz
- Excellent Linearity: +32 dB Input IP3
- Wide Attenuation Range: 35 dB
- No External Matching
- 24 Lead 4x4 mm SMT Package: 16 mm<sup>2</sup>

### General Description

The HMC985LP4KE is an absorptive Voltage Variable Attenuator (VVA) which operates from 10 - 40 GHz and is ideal in designs where an analog DC control signal must be used to control RF signal levels over a 35 dB dynamic range. It features two shunt-type attenuators which are controlled by two analog voltages, Vctl1 and Vctl2. Optimum linearity performance of the attenuator is achieved by first varying Vctl1 of the first attenuation stage from -3V to 0V with Vctl2 fixed at -3V. The control voltage of the second attenuation stage, Vctl2, should then be varied from -3V to 0V with Vctl1 fixed at 0V.

if the Vctl1 and Vctl2 pins are connected together it is possible to achieve the full analog attenuation range with only a small degradation in input IP3 performance. Applications include AGC circuits and temperature compensation of multiple gain stages in microwave point-to-point and VSAT radios.

### Electrical Specifications, $T_A = +25^\circ\text{C}$ , Test Condition $V_{ctl1} = V_{ctl2}$

| Parameter   | Frequency   | Min. | Typ. | Max. | Units |
|---|-------------|------|------|------|-------|
| Insertion Loss <sup>[1]</sup>   | 10 - 20 GHz |      | 3    | 3.5  | dB    |
|   | 20 - 30 GHz |      | 3    | 4    | dB    |
|   | 30 - 40 GHz |      | 3.5  | 4.5  | dB    |
| Attenuation Range   | 10 - 20 GHz | 25   | 30   |      | dB    |
|   | 20 - 30 GHz | 30   | 35   |      | dB    |
|   | 30 - 40 GHz | 35   | 40   |      | dB    |
| Input Return Loss   | 10 - 40 GHz |      | 13   |      | dB    |
| Output Return Loss  | 10 - 40 GHz |      | 13   |      | dB    |
| Input Third Order Intercept<br>(two-tone input Power = 10 dBm Each Tone) <sup>[2]</sup> |             |      | 33   |      | dBm   |

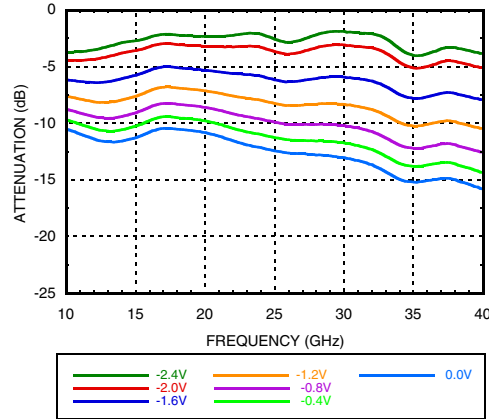
[1] Vctl1 = Vctl2 = -2.4V

[2] Vctl1 = Vctl2 = -2.0V worst case

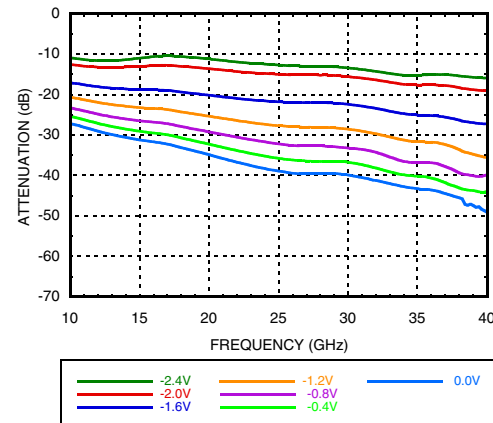


**GaAs MMIC VOLTAGE - VARIABLE  
ATTENUATOR, 10 - 40 GHz**

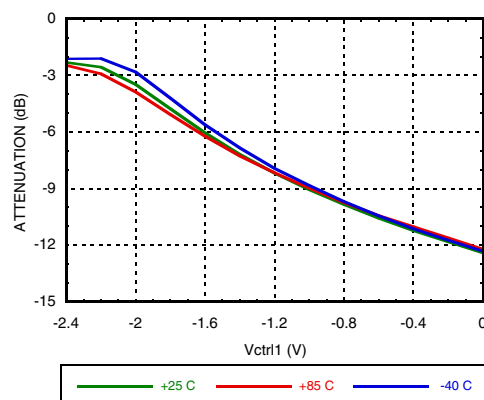
**Attenuation vs. Frequency over  $V_{ctrl1}$  = Variable,  $V_{ctrl2} = -3V$**



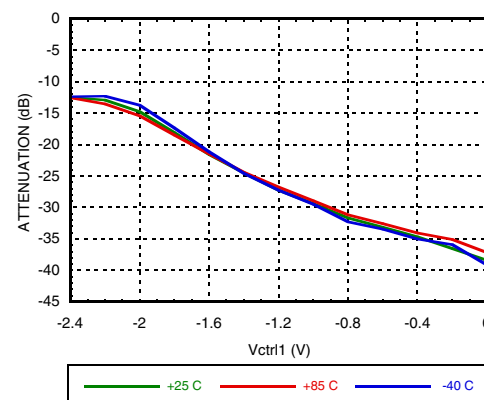
**Attenuation vs. Frequency over  $V_{ctrl1} = 0V$ ,  $V_{ctrl2}$  = Variable**



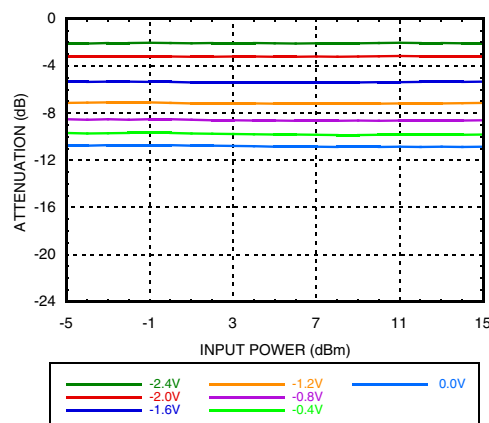
**Attenuation vs.  $V_{ctrl1}$   
Over Temperature @ 25 GHz,  $V_{ctrl2} = -3V$**



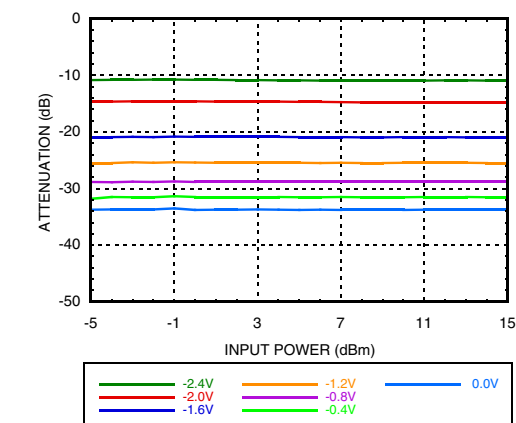
**Attenuation vs.  $V_{ctrl2}$   
Over Temperature @ 30 GHz,  $V_{ctrl1} = 0V$**



**Attenuation vs.  $P_{in}$  @ 20 GHz over  $V_{ctrl1}$   
 $V_{ctrl1}$  = Variable,  $V_{ctrl2} = -3V$**



**Attenuation vs.  $P_{in}$  @ 20 GHz over  $V_{ctrl2}$   
 $V_{ctrl2}$  = Variable,  $V_{ctrl1} = 0V$**

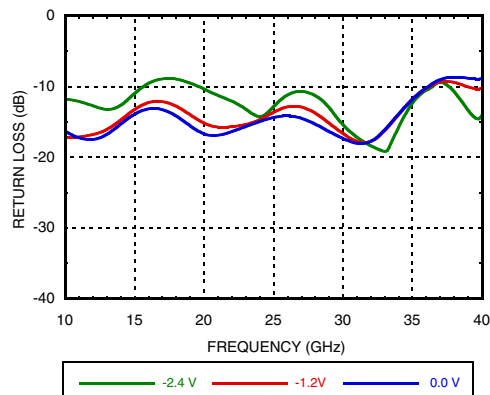




# GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

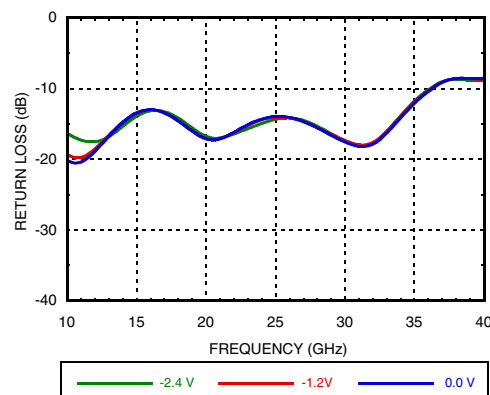
## Input Return Loss

**Vctl1 = Variable, Vctl2 = -3V**



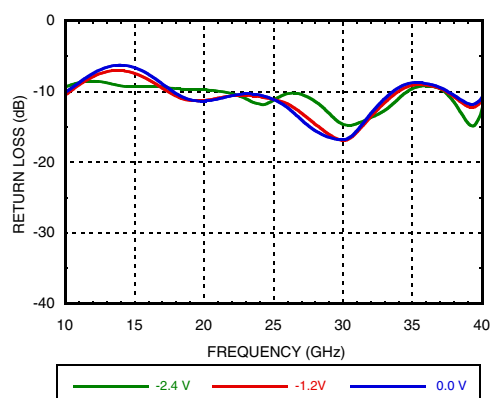
## Input Return Loss

**Vctl1 = 0V, Vctl2 = Variable**



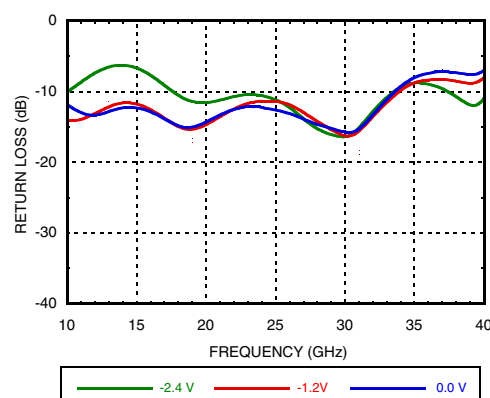
## Output Return Loss

**Vctl1 = Variable, Vctl2 = -3V**



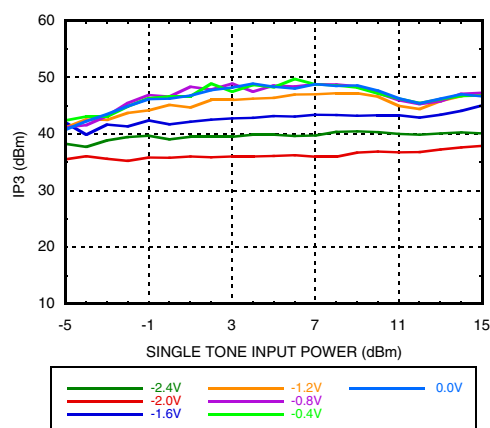
## Output Return Loss

**Vctl1 = 0V, Vctl2 = Variable**



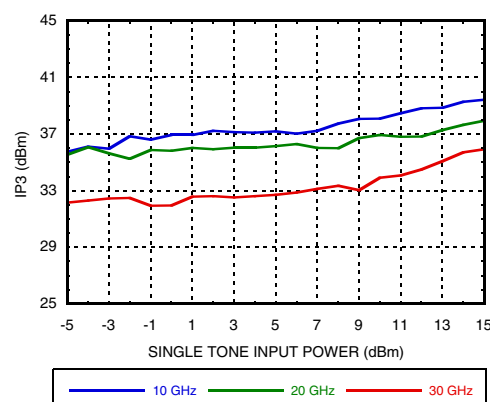
## Input IP3 vs. Input Power @ 20 GHz

**Vctl1 = Variable, Vctl2 = -3V**



## Input IP3 vs. Input Power Over Frequency

**Vctl1 = -2V, Vctl2 = -3V [1]**

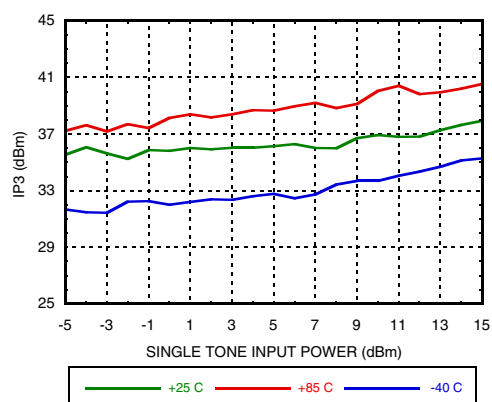


[1] Worst Case IP3

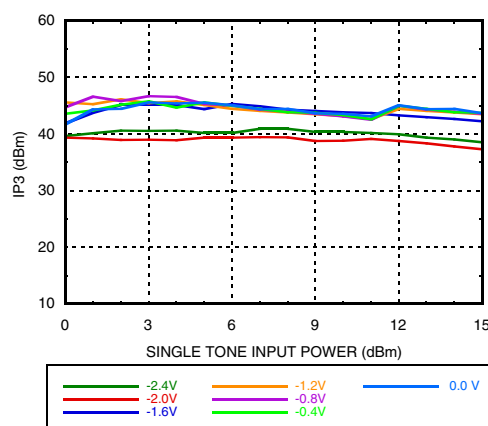


## GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

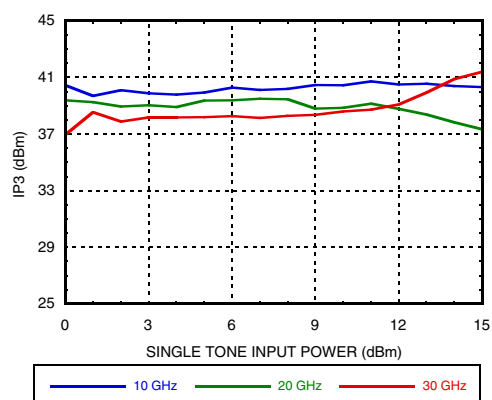
**Input IP3 vs. Input Power Over Temperature  
@ 20 GHz, Vctl1 = -2V, Vctl2 = -3V [1]**



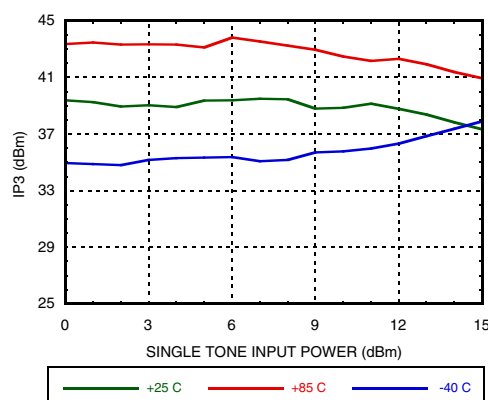
**Input IP3 vs. Input Power @ 20 GHz  
Vctl2 = Variable, Vctl1 = 0V**



**Input IP3 vs. Input Power Over Frequency  
Vctl2 = -2V, Vctl1 = 0V [1]**



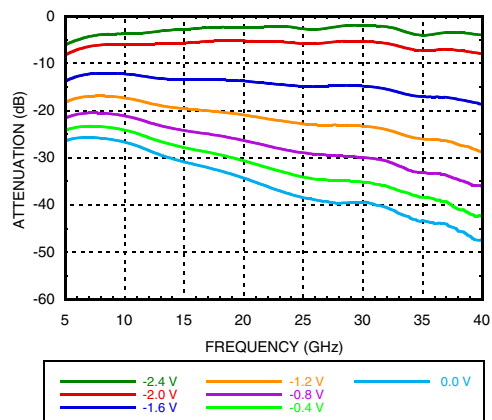
**Input IP3 vs Input Power over Temperature  
@ 20 GHz, Vctl2 = -2V, Vctl1 = 0V [1]**



[1] Worst Case IP3

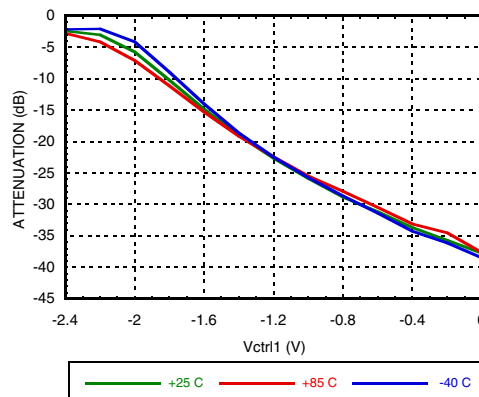


**Attenuation vs Frequency Over Vctrl**  
Vctrl1 = Vctrl2

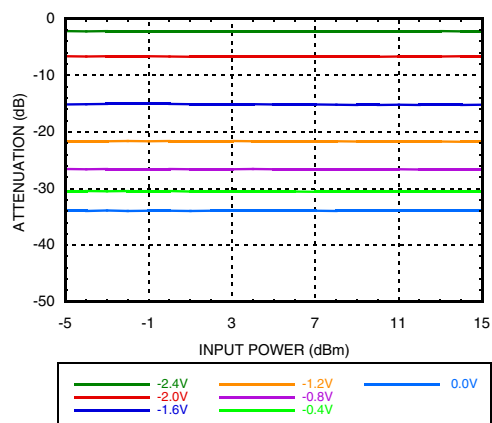


**GaAs MMIC VOLTAGE - VARIABLE  
ATTENUATOR, 10 - 40 GHz**

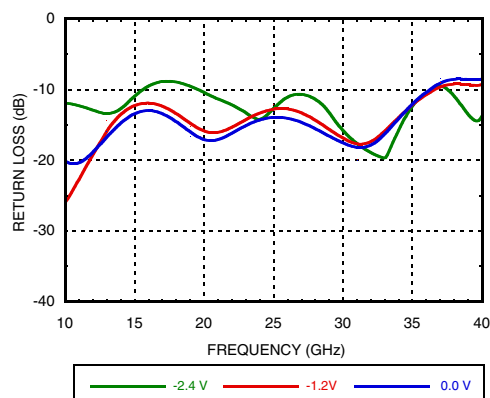
**Attenuation vs. Vctrl Over Temperature**  
@ 20 GHz, Vctrl1 = Vctrl2



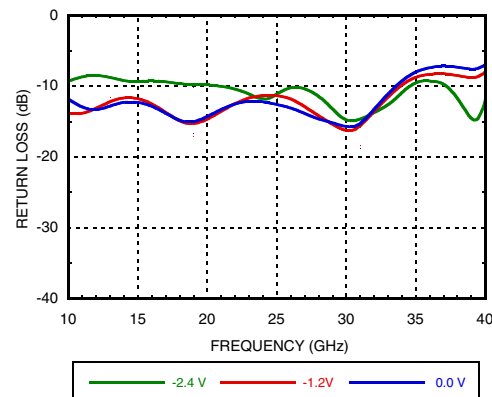
**Attenuation vs. Pin @ 20 GHz Over Vctrl**  
Vctrl1 = Vctrl2



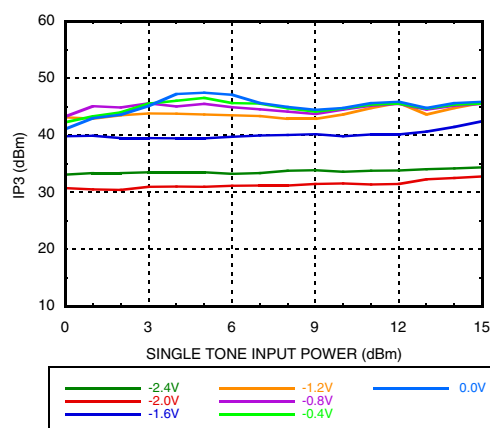
**Input Return Loss, Vctrl1 = Vctrl2**



**Output Return Loss, Vctrl1 = Vctrl2**

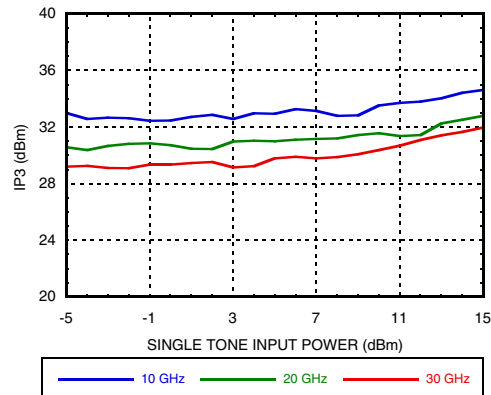


**Input IP3 vs. Input Power Over Vctrl @ 20 GHz, Vctrl1 = Vctrl2**



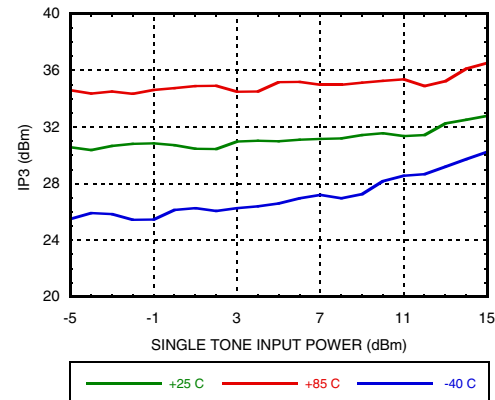


**Input IP3 vs. Input Power Over Frequency**  
**Vctl1 = Vctl2**



**GaAs MMIC VOLTAGE - VARIABLE  
ATTENUATOR, 10 - 40 GHz**

**Input IP3 vs. Input Power Over  
Temperature @ 20 GHz Vctl1 = Vctl2**





## GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

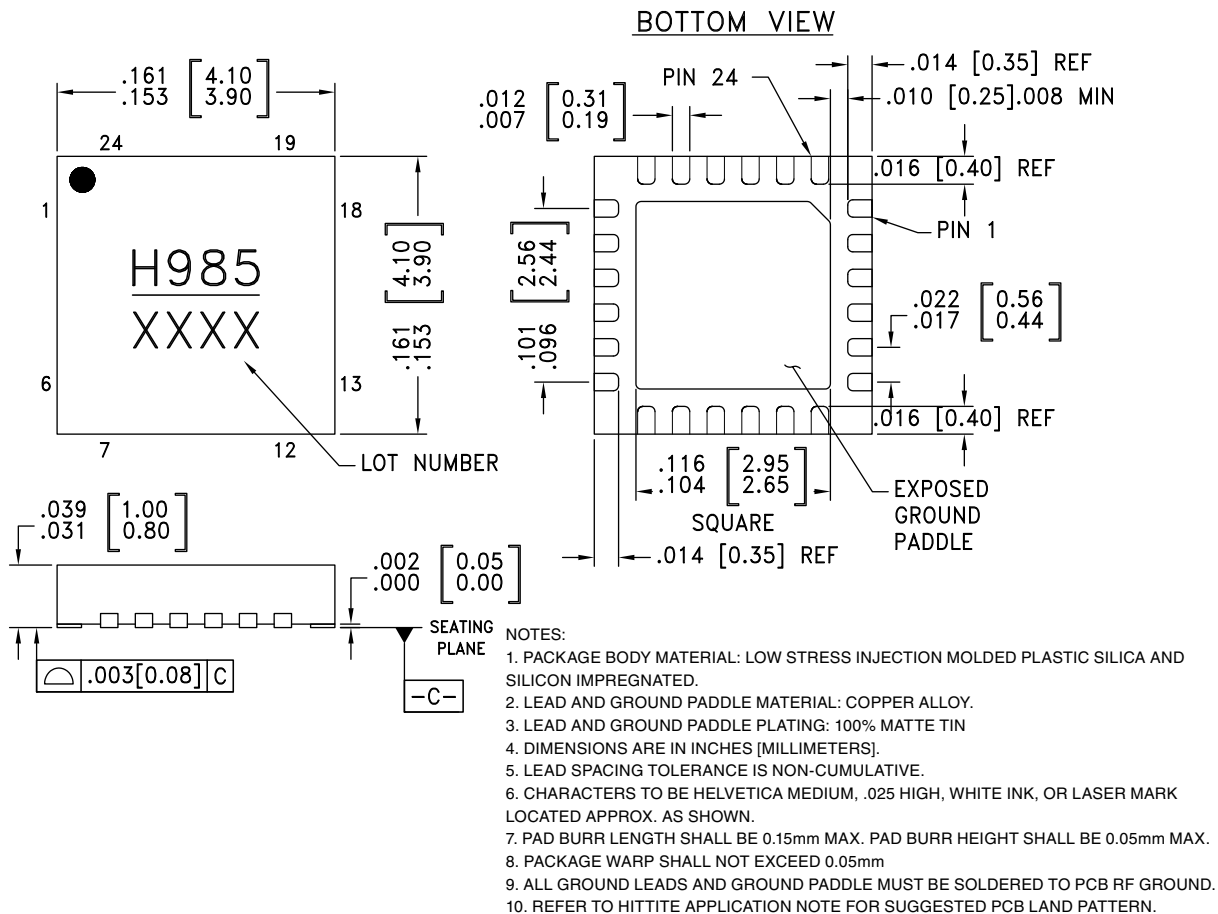
### Absolute Maximum Ratings

|  |                      |
|--|----------------------|
| Control Voltage  | +1 to -5V            |
| Input RF Power   | 30 dBm               |
| Maximum Junction Temperature                                   | 165 °C               |
| Thermal Resistance ( $R_{TH}$ )<br>(junction to ground paddle) | 62 °C/W              |
| Operating Temperature  | -40°C to +85°C       |
| Storage Temperature  | -65°C to 125°C       |
| ESD Sensitivity (HBM)  | Class1A, passed 250V |



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing



### Package Information

| Part Number | Package Body Material                              | Lead Finish   | MSL Rating          | Package Marking |
|-------------|--|---------------|---------------------|-----------------|
| HMC985LP4KE | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 <sup>[1]</sup> | H985<br>XXX     |


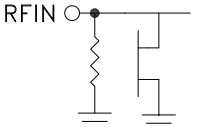
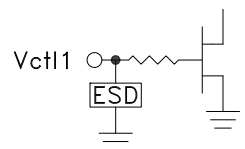
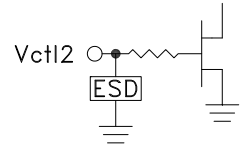
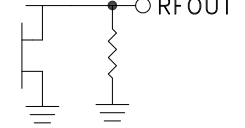
[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

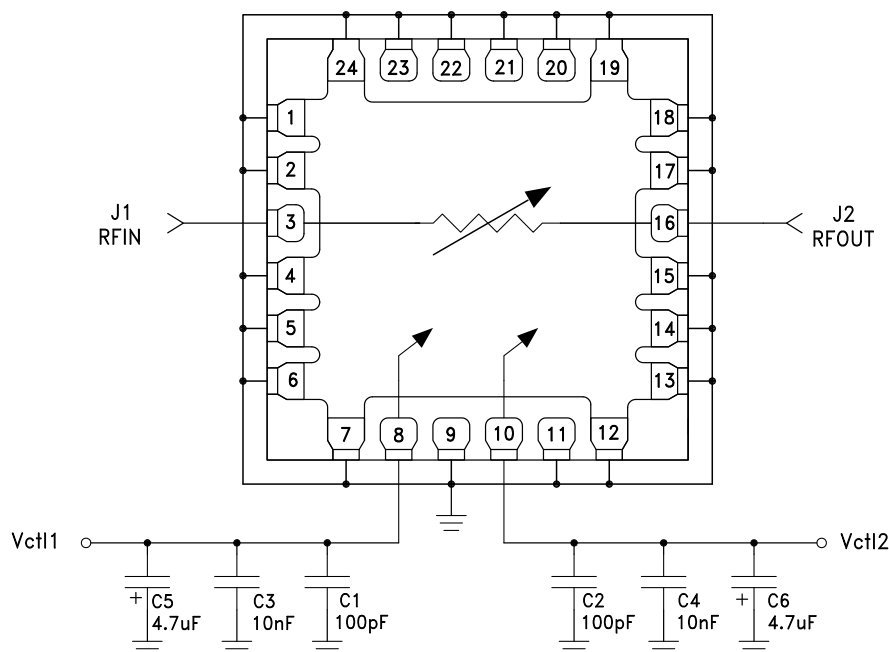


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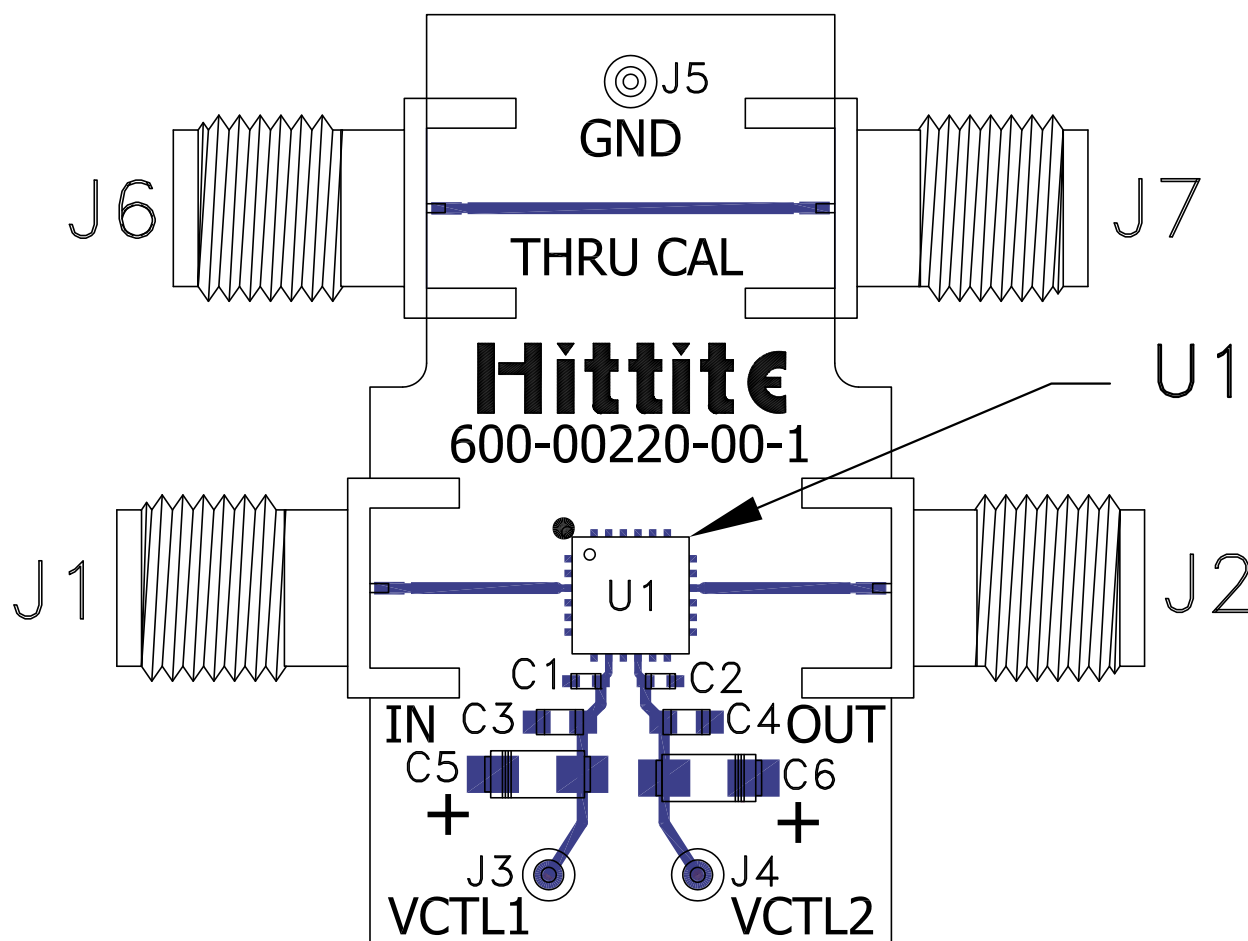
### Pin Descriptions

| Pin Number                  | Function | Description   | Pin Schematic   |
|-----------------------------|----------|---|---|
| 1, 2, 4-7, 12-15, 17-19, 24 | GND      | These pins and package bottom must be connected to RF/DC ground externally.   |    |
| 3                           | RFIN     | This pad is DC coupled and matched to 50 Ohms.  |    |
| 8                           | Vctl1    | Control Voltage 1.  |    |
| 9, 11, 20-23                | NC       | These pins are not connected internally, however all data shown herein was measured with these pins connected to RF/DC ground externally. |   |
| 10                          | Vctl2    | Control Voltage 2.  |   |
| 16                          | RFOUT    | This pad is DC coupled and matched to 50 Ohms.  |  |

### Application Circuit






**GaAs MMIC VOLTAGE - VARIABLE  
ATTENUATOR, 10 - 40 GHz**
**Evaluation PCB**

**List of Materials for Evaluation PCB EVAL01-HMC985LP4KE <sup>[1]</sup>**

| Item         | Description                       |
|--------------|-----------------------------------|
| J1-J2, J6-J7 | K Connectors.                     |
| J3-J5        | DC Pins.                          |
| C1-C2        | 100pF Capacitors, 0402 Pkg.       |
| C3-C4        | 0.01 $\mu$ F Capacitor, 0603 Pkg. |
| C5-C6        | 4.7 $\mu$ F Case A, Tantalum.     |
| U1           | HMC985LP4KE VVA.                  |
| PCB          | 600-00220-00 Evaluation PCB.      |

[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

**GaAs MMIC VOLTAGE - VARIABLE  
ATTENUATOR, 10 - 40 GHz****Notes:**

## Данный компонент на территории Российской Федерации

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Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

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Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

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